

**For Scintillation Counting and High Energy Physics
38 mm (1-1/2 Inch) Diameter, 10-stage, Bialkali Photocathode, Head-on Type**

GENERAL

Parameter		Description	Unit
Spectral Response		300 to 650	nm
Wavelength of Maximum Response		420	nm
Photocathode	Material	Bialkali	—
	Minimum Effective Area	φ34	mm
Window Material		Borosilicate glass	—
Dynode	Structure	Linear focused	—
	Number of Stages	10	—
Direct Interelectrode	Anode to Last Dynode	3	pF
Capacitances	Anode to All Other Electrodes	7	pF
Operating Ambient Temperature		-30 to +50	°C
Storage Temperature		-30 to +50	°C
Base		JEDEC No. B12-43	—
Suitable Socket		E678-12A (supplied)	—

MAXIMUM RATINGS (Absolute Maximum Values)

Parameter		Value	Unit
Supply Voltage	Between Anode and Cathode	1750	V
	Between Anode and Last Dynode	350	V
Average Anode Current		0.1	mA

CHARACTERISTICS (at 25 °C)

Parameter		Min.	Typ.	Max.	Unit
Cathode Sensitivity	Luminous (2856 K)	70	95	—	μA/lm
	Radiant at 420 nm	—	88	—	mA/W
	Blue Sensitivity Index (CS 5-58)	9	11	—	—
	Quantum Efficiency at 420 nm	—	27	—	%
Anode Sensitivity	Luminous (2856 K)	10	100	—	A/lm
Gain		—	1.1 × 10 ⁶	—	—
Anode Dark Current (after 30 min storage in darkness)		—	3	20	nA
Time Response	Anode Pulse Rise Time	—	2.7	—	ns
	Electron Transit Time	—	37	—	ns
	Transit Time Spread (FWHM)	—	4.5	—	ns
Pulse Linearity (±2 % deviation)		—	150	—	mA

NOTE: Anode characteristics are measured with the voltage distribution ratio shown below.

VOLTAGE DISTRIBUTION RATIO AND SUPPLY VOLTAGE

Electrodes	K	Dy1	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	P
Ratio	2	1	1	1	1	1	1	1	1	1	1	1

Supply Voltage : 1250 Vdc, K : Cathode, Dy : Dynode, P : Anode

SPECIAL VOLTAGE DISTRIBUTION RATIO FOR PULSE LINEARITY MEASUREMENT

Electrodes	K	Dy1	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	P
Ratio	2	1	1	1	1	1	1.2	1.5	2.2	3.6	3	
Parallel Capacitors in μF									0.01	0.02	0.04	0.06

Supply Voltage : 1500 Vdc

PHOTOMULTIPLIER TUBE R580

Figure 1: Typical Spectral Response

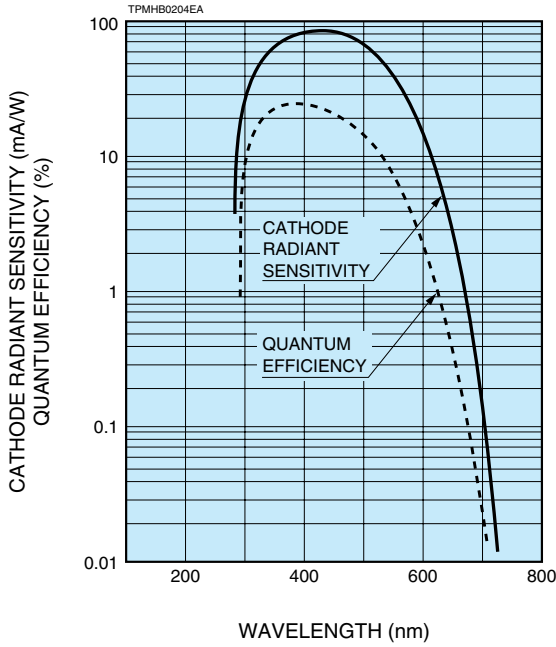
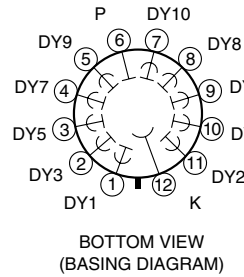
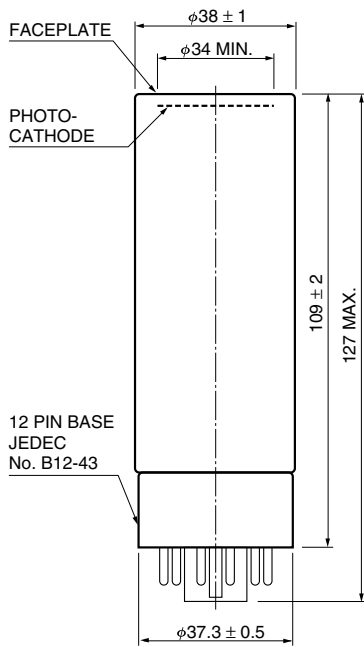
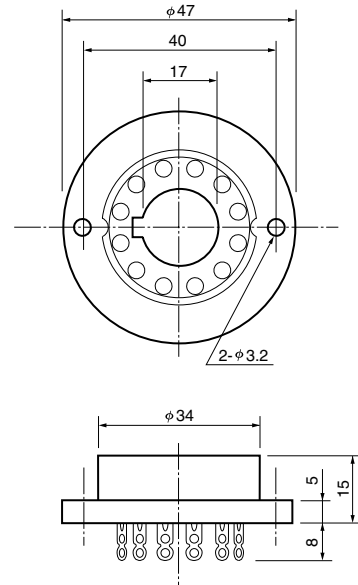


Figure 2: Dimensional Outline and Basing Diagram (Unit: mm)



Socket E678-12A
(Supplied)



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TPMH1100E03
DEC. 2010 IP